

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("20040218109").PN.	US-PGPUB; USPAT	OR	OFF	2006/05/15 03:19
L2	0	(heterogeneous near straight) AND ((crystal\$5 adj2 boundary) with straight) AND ((semiconductive adj channel) (channel)) AND ((thin adj film adj transistor) TFT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/15 03:21
L3	3	((heterogeneous near straight) ((crystal\$5 adj2 boundary) with straight)) AND ((semiconductive adj channel) (channel)) AND ((thin adj film adj transistor) TFT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/15 03:25
L4	1135	((heterogeneous near straight) (crystal\$5 adj2 boundary)) AND ((semiconductive adj channel) (channel)) AND ((thin adj film adj transistor) TFT)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/15 03:26
L5	290	4 and (349/42-43.ccls. 257/59,66, 72,74.ccls. 345/92.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/15 03:25
L6	34	((((heterogeneous near straight) (crystal\$5 adj2 boundary)) AND ((semiconductive adj channel) (channel)) AND ((thin adj film adj transistor) TFT)).CLM.	US-PGPUB	OR	ON	2006/05/15 03:26